

2N5246

N-Channel RF Amplifier

- This device is designed for HF/VHF mixer/amplifier and applications where process 50is not adequate. Sufficient gain and low noise for sensitive receivers.
- Sourced from process 90.



Absolute Maximum Ratings* T_a =25°C unless otherwise noted

| Symbol | Parameter | Ratings | Units |
|-----------------------------------|--|-----------|-------|
| V_{DG} | Drain-Gate Voltage | 30 | V |
| V _{GS} | Gate-Source Voltage | -30 | V |
| I _{GF} | Forward Gate Current | 10 | mA |
| T _J , T _{STG} | Operating and Storage Junction Temperature Range | -55 ~ 150 | °C |

^{*} This ratings are limiting values above which the serviceability of any semiconductor device may be impaired.

- These rating are based on a maximum junction temperature of 150 degrees C.
 These are steady limits. The factory should be consulted on applications involving pulsed or low duty cycle operations.

Electrical Characteristics T_a=25°C unless otherwise noted

| Symbol | Parameter | Test Condition | Min. | Max. | Units |
|------------------------------|-----------------------------------|--|------|------|-------|
| Off Charac | teristics | | | | |
| V _{(BR)GSS} | Gate-Source Breakdwon Voltage | $I_G = 1.0 \mu A, V_{DS} = 0$ | -30 | | V |
| I _{GSS} | Gate Reverse Current | $V_{GS} = 25V, V_{DS} = 0$ | | -1.0 | nA |
| V _{GS(off)} | Gate-Source Cutoff Voltage | $V_{DS} = 15V, I_{D} = 1.0nA$ | -0.5 | -4.0 | V |
| On Characteristics | | | | | |
| I _{DSS} | Zero-Gate Voltage Drain Current * | V _{DS} = 15V, V _{GS} = 0 | 1.5 | 7.0 | mA |
| Small Signal Characteristics | | | | | |
| gfs | Forward Transferconductance | $V_{GS} = 0V, V_{DS} = 15V, f = 1.0kHz$ | 3000 | 9500 | μmhos |
| goss | Common- Source Output Conductance | $V_{GS} = 0V, V_{DS} = 15V, f = 1.0kHz$ | | 50 | μmhos |

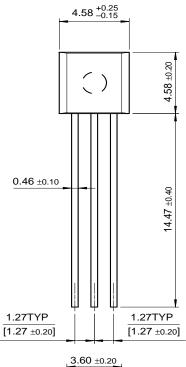
^{*} Pulse Test: Pulse ≤ 300μs

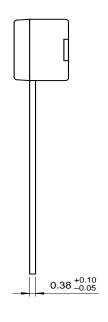
Thermal Characteristics T_A=25°C unless otherwise noted

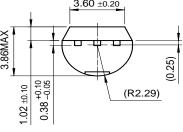
| Symbol | Parameter | Max. | Units |
|-----------------|---|------|-------|
| P_{D} | Total Device Dissipation | 350 | mW |
| | Derate above 25°C | 2.8 | mW/°C |
| $R_{\theta JC}$ | Thermal Resistance, Junction to Case | 125 | °C/W |
| $R_{\theta JA}$ | Thermal Resistance, Junction to Ambient | 357 | °C/W |

Package Dimensions

TO-92







TRADEMARKS

The following are registered and unregistered trademarks Fairchild Semiconductor owns or is authorized to use and is not intended to be an exhaustive list of all such trademarks.

| ActiveArray TM Bottomless TM CoolFET TM CROSSVOLT TM DOME TM EcoSPARK TM E²CMOS TM EnSigna TM FACT TM | FACT Quiet Series™ FAST® FASTr™ FRFET™ GlobalOptoisolator™ GTO™ HiSeC™ ²C™ ImpliedDisconnect™ ISOPLANAR™ Around the world.™ ise™ | LittleFETTM MICROCOUPLERTM MicroFETTM MicroPakTM MICROWIRETM MSXTM MSXPROTM OCXTM OCXTM OCXPROTM OPTOLOGIC® OPTOPLANARTM PACMANTM | Power247 TM PowerTrench [®] QFET [®] QS TM QT Optoelectronics TM Quiet Series TM RapidConfigure TM RapidConnect TM SILENT SWITCHER [®] SMART START TM SPM TM Stealth TM | SuperSOT™-6 SuperSOT™-8 SyncFET™ TinyLogic® TINYOPTO™ TruTranslation™ UHC™ UltraFET® VCX™ |
|--|---|---|---|---|
| The Power Franch Programmable Act | | PACMAN™ POP™ | Stealth™ SuperSOT™-3 | |
| | | | | |

DISCLAIMER

FAIRCHILD SEMICONDUCTOR RESERVES THE RIGHT TO MAKE CHANGES WITHOUT FURTHER NOTICE TO ANY PRODUCTS HEREIN TO IMPROVE RELIABILITY, FUNCTION OR DESIGN. FAIRCHILD DOES NOT ASSUME ANY LIABILITY ARISING OUT OF THE APPLICATION OR USE OF ANY PRODUCT OR CIRCUIT DESCRIBED HEREIN; NEITHER DOES IT CONVEY ANY LICENSE UNDER ITS PATENT RIGHTS, NOR THE RIGHTS OF OTHERS.

LIFE SUPPORT POLICY

FAIRCHILD'S PRODUCTS ARE NOT AUTHORIZED FOR USE AS CRITICAL COMPONENTS IN LIFE SUPPORT DEVICES OR SYSTEMS WITHOUT THE EXPRESS WRITTEN APPROVAL OF FAIRCHILD SEMICONDUCTOR CORPORATION.

As used herein:

- 1. Life support devices or systems are devices or systems which, (a) are intended for surgical implant into the body, or (b) support or sustain life, or (c) whose failure to perform when properly used in accordance with instructions for use provided in the labeling, can be reasonably expected to result in significant injury to the user.
- 2. A critical component is any component of a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or system, or to affect its safety or effectiveness.

PRODUCT STATUS DEFINITIONS

Definition of Terms

| Datasheet Identification | Product Status | Definition |
|--------------------------|---------------------------|---|
| Advance Information | Formative or In Design | This datasheet contains the design specifications for product development. Specifications may change in any manner without notice. |
| Preliminary | First Production | This datasheet contains preliminary data, and supplementary data will be published at a later date. Fairchild Semiconductor reserves the right to make changes at any time without notice in order to improve design. |
| No Identification Needed | Full Production | This datasheet contains final specifications. Fairchild Semiconductor reserves the right to make changes at any time without notice in order to improve design. |
| Obsolete | Not In Production | This datasheet contains specifications on a product that has been discontinued by Fairchild semiconductor. The datasheet is printed for reference information only. |

©2003 Fairchild Semiconductor Corporation Rev.